

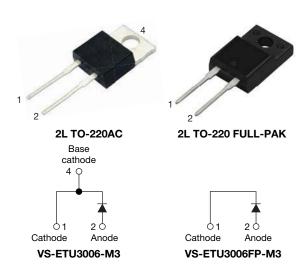
Vishay Semiconductors

RoHS

**HALOGEN** 

FREE

# Ultrafast Rectifier, 30 A FRED Pt®



PRODUCT SUMMARY					
Package	2L TO-220AC, 2L TO-220FP				
I <sub>F(AV)</sub>	30 A				
$V_{R}$	600 V				
V <sub>F</sub> at I <sub>F</sub>	1.15 V				
t <sub>rr</sub> (typ.)	30 ns				
T <sub>J</sub> max.	175 °C				
Diode variation	Single die				

#### **FEATURES**

- · Low forward voltage drop
- · Ultrafast soft recovery time
- 175 °C operating junction temperature
- · Low leakage current
- Fully isolated package (V<sub>INS</sub> = 2500 V<sub>RMS</sub>)
- True 2 pin package
- Designed and qualified according to JEDEC®-JESD 47
- Material categorization: for definitions of compliance please see <a href="https://www.vishav.com/doc?99912"><u>www.vishav.com/doc?99912</u></a>



Ultralow  $V_F$ , soft-switching ultrafast rectifiers optimized for Discontinuous (Critical) Mode (DCM) Power Factor Correction (PFC).

The minimized conduction loss, optimized stored charge and low recovery current minimized the switching losses and reduce over dissipation in the switching element and snubbers.

The device is also intended for use as a freewheeling diode in power supplies and other power switching applications.

#### **APPLICATIONS**

AC/DC SMPS 70 W to 400 W

e.g. laptop and printer AC adaptors, desktop PC, TV and monitor, games units and DVD AC/DC power supplies.

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Peak repetitive reverse voltage	V <sub>RRM</sub>		600	V		
Average rectified forward current in DC ———————————————————————————————————	I <sub>F(AV)</sub>	T <sub>C</sub> = 130 °C	30	А		
FULL-PAK		T <sub>C</sub> = 72 °C	30			
Non-repetitive peak surge current	I <sub>FSM</sub>	T <sub>J</sub> = 25 °C	200			
Operating junction and storage temperatures	T <sub>J</sub> , T <sub>Stg</sub>		-65 to +175	°C		

<b>ELECTRICAL SPECIFICATIONS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS	TYP.	MAX.	UNITS		
Breakdown voltage, blocking voltage	V <sub>BR</sub> , V <sub>R</sub>	Ι <sub>R</sub> = 100 μΑ	600	-	-		
Forward voltage	V <sub>F</sub>	I <sub>F</sub> = 30 A	-	1.4	2.0	V	
		I <sub>F</sub> = 30 A, T <sub>J</sub> = 150 °C	-	1.15	1.35		
Reverse leakage current I <sub>R</sub>		$V_R = V_R$ rated	-	0.02	30	μA	
		T <sub>J</sub> = 150 °C, V <sub>R</sub> = V <sub>R</sub> rated	=	30	250	μΑ	
Junction capacitance	C <sub>T</sub>	V <sub>R</sub> = 600 V	-	20	-	pF	
Series inductance	L <sub>S</sub>	Measured lead to lead 5 mm from package body	-	8	-	nH	



# VS-ETU3006-M3, VS-ETU3006FP-M3

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<b>DYNAMIC RECOVERY CHARACTERISTICS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CO	MIN.	TYP.	MAX.	UNITS	
	$I_F = 1 \text{ A, } dI_F/dt = 50 \text{ A}$		A/μs, V <sub>R</sub> = 30 V	-	30	45	
Reverse recovery time	t <sub>rr</sub>	T <sub>J</sub> = 25 °C		-	45	-	ns
		T <sub>J</sub> = 125 °C		-	100	-	
Dools woods on a surrount		T <sub>J</sub> = 25 °C	I <sub>F</sub> = 30 A dI <sub>F</sub> /dt = 200 A/μs V <sub>B</sub> = 200 V	-	5.6	-	А
Peak recovery current	IRRM	T <sub>J</sub> = 125 °C		-	10	-	
Reverse recovery charge	Q <sub>rr</sub>	T <sub>J</sub> = 25 °C	,,,	-	127	-	nC
		T <sub>J</sub> = 125 °C		-	580	-	

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Maximum junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		-65	-	175	°C	
Thermal resistance,	ב		ı	0.84	1.3		
junction to case FULL-PAK	$R_{thJC}$		-	3.2	3.8		
Thermal resistance, junction to ambient	R <sub>thJA</sub>	Typical socket mount	-	-	70	°C/W	
Typical thermal resistance, case to heatsink	R <sub>thCS</sub>	Mounting surface, flat, smooth and greased	-	0.5	-		
Weight			-	2	-	g	
Weight			-	0.07	-	oz.	
Mounting torque			6 (5)	-	12 (10)	kgf · cm (lbf · in)	
Madina davia		Case style 2L TO-220AC	ETU3006		•		
Marking device		Case style 2L TO-220 FULL-PAK		ETU3	006FP		

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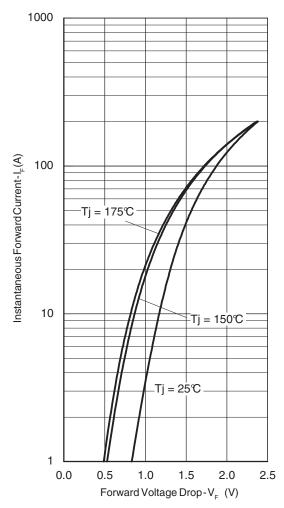


Fig. 1 - Typical Forward Voltage Drop Characteristics

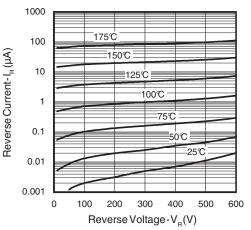


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

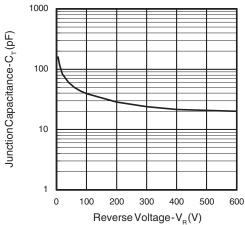


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

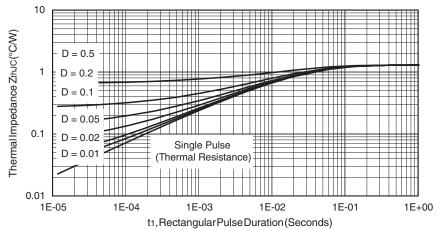


Fig. 4 - Maximum Thermal Impedance Z<sub>thJC</sub> Characteristics

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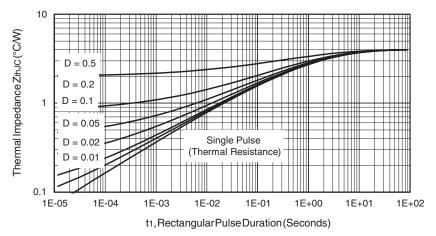


Fig. 5 - Maximum Thermal Impedance Z<sub>thJC</sub> Characteristics (FULL-PAK)

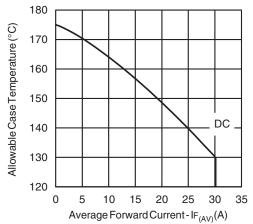


Fig. 6 - Maximum Allowable Case Temperature vs. Average Forward Current

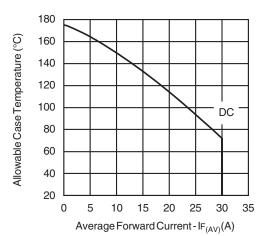
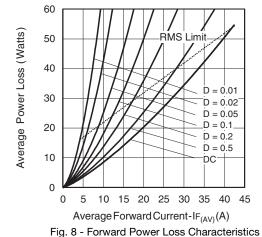


Fig. 7 - Maximum Allowable Case Temperature vs. Average Forward Current (FULL-PAK)





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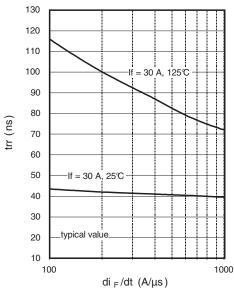


Fig. 9 - Typical Reverse Recovery vs. dl<sub>F</sub>/dt

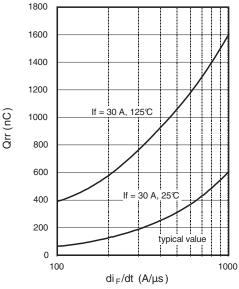
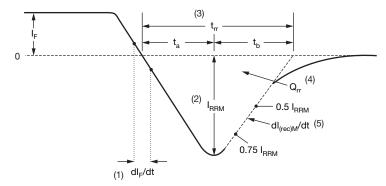


Fig. 10 - Typical Stored Charge vs. dl<sub>F</sub>/dt



- (1) dl<sub>F</sub>/dt rate of change of current through zero crossing
- (2)  $I_{RRM}$  peak reverse recovery current
- (3)  $\rm t_{rr}$  reverse recovery time measured from zero crossing point of negative going  $\rm l_F$  to point where a line passing through 0.75  $\rm l_{RRM}$  and 0.50  $\rm l_{RRM}$  extrapolated to zero current.
- (4)  $\mathbf{Q}_{rr}$  area under curve defined by  $\mathbf{t}_{rr}$  and  $\mathbf{I}_{RRM}$

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

(5) dI<sub>(rec)M</sub>/dt - peak rate of change of current during t<sub>b</sub> portion of t<sub>rr</sub>

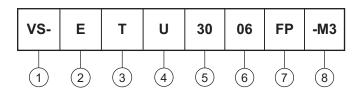
Fig. 11 - Reverse Recovery Waveform and Definitions

## VS-ETU3006-M3, VS-ETU3006FP-M3

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#### **ORDERING INFORMATION TABLE**

Device code



1 - Vishay Semiconductors product

2 - Circuit configuration:

E = single diode

**3** - T = TO-220

U = hyperfast recovery time

Current code: 30 = 30 A

6 - Voltage code: 06 = 600 V

7 - • None = TO-220

• FP = FULL-PAK

8 - Environmental digit:

-M3 = halogen-free, RoHS-compliant and terminations lead (Pb)-free

ORDERING INFORMATION (Example)						
PREFERRED P/N	QUANTITY PER TUBE	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION			
VS-ETU3006-M3	50	1000	Antistatic plastic tube			
VS-ETU3006FP-M3	50	1000	Antistatic plastic tube			

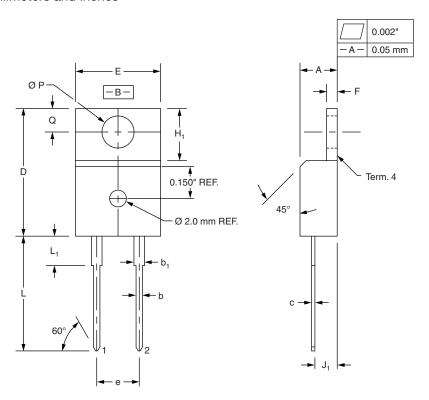
LINKS TO RELATED DOCUMENTS					
Dimensions	2L TO-220AC	www.vishay.com/doc?95259			
Diffiensions	2L TO-220 FULL-PAK	www.vishay.com/doc?95260			
Part marking information	2L TO-220AC	www.vishay.com/doc?95391			
Part marking information	2L TO-220 FULL-PAK	www.vishay.com/doc?95392			



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## True 2 Pin TO-220

#### **DIMENSIONS** in millimeters and inches



SYMBOL	MILLIM	METERS	INC	HES
STMBOL	MIN.	MAX.	MIN.	MAX.
А	4.32	4.57	0.170	0.180
b	0.71	0.91	0.028	0.036
b <sub>1</sub>	1.15	1.39	0.045	0.055
С	0.36	0.53	0.014	0.021
D	14.99	15.49	0.590	0.610
Е	10.04	10.41	0.395	0.410
е	5.08	BSC	0.200 BSC	
F	1.22	1.37	0.048	0.054
H <sub>1</sub>	5.97	6.47	0.235	0.255
J <sub>1</sub>	2.54	2.79	0.100	0.110
L	13.47	13.97	0.530	0.550
L <sub>1</sub> <sup>(1)</sup>	3.31	3.81	0.130	0.150
Ø P	3.79	3.88	0.149	0.153
Q	2.60	2.84	0.102	0.112

#### Notes

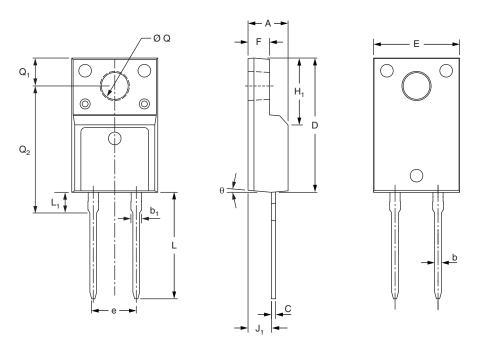
- $^{\left(1\right)}$  Lead dimension and finish uncontrolled in L<sub>1</sub>
- These dimensions are within allowable dimensions of JEDEC TO-220AB rev. J outline dated 3-24-87
- Controling dimension: Inch



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## True 2 Pin TO-220 FULL-PAK

#### **DIMENSIONS** in millimeters and inches



SYMBOL	MILLI	METERS	INC	HES
STMBOL	MIN.	MAX.	MIN.	MAX.
A	4.53	4.93	0.178	0.194
b	0.71	0.91	0.028	0.036
b <sub>1</sub>	1.15	1.39	0.045	0.055
С	0.36	0.53	0.014	0.021
D	15.67	16.07	0.617	0.633
E	9.96	10.36	0.392	0.408
е	5.08	typical	0.200	typical
F	2.34	2.74	0.092	0.107
H <sub>1</sub>	6.50	6.90	0.256	0.272
J <sub>1</sub>	2.56	2.96	0.101	0.117
L	12.78	13.18	0.503	0.519
L <sub>1</sub>	2.23	2.63	0.088	0.104
ØQ	2.98	3.38	0.117	0.133
Q <sub>1</sub>	3.10	3.50	0.122	0.138
$Q_2$	14.80	15.20	0.583	0.598
θ	0°	5°	0°	5°



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